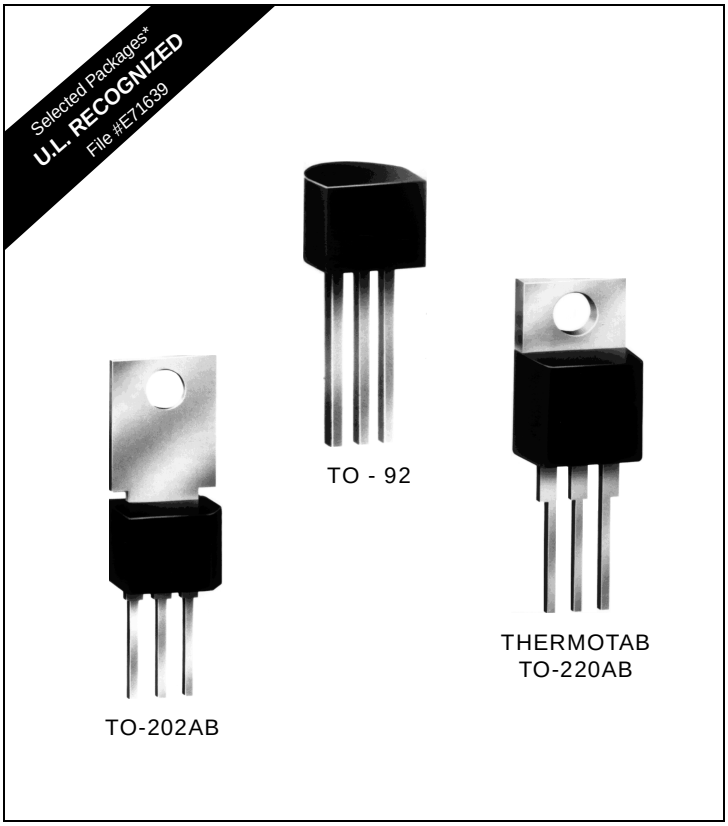
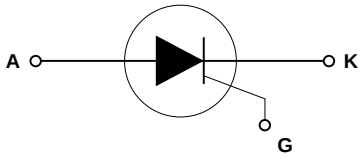




Sensitive SCRs

(0.8 – 10 Amps)

General Description

The Teccor Electronics, Inc. line of sensitive SCR semiconductors are half-wave unidirectional gate-controlled rectifiers (SCR-thyristor) which complement Teccor's line of power SCRs. This group of packages offers ratings of 0.8-10 amps, and 50-600 volts with gate sensitivities of 12-500 microamps. If gate currents in the 10-50 milliamp ranges are required, please consult Teccor's non-sensitive SCR technical data sheets.

Electrically Isolated Packages

This group of Teccor sensitive SCRs is available in a choice of three different product packages. The TO-220AB and TO-92 are electrically isolated where the case or tab is internally isolated to allow the use of low cost assembly and convenient packaging techniques.

Glass Passivation

Teccor's line of SCRs features glass-passivated junctions to ensure long term device reliability and parameter stability. Teccor's glass offers a rugged, reliable barrier against junction contamination.

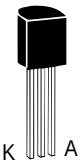
Tape-and-reel packaging is available for the TO-92 package. Please consult factory for more information.

Variations of devices covered in this data sheet are available for custom design applications. Please consult the factory for more information.

Features

- **Electrically-isolated To-220AB package**
- **High Voltage Capability up to 600 Volts**
- **High Surge Capability — up to 100 Amps**
- **Glass Chip Passivation**

Electrical Specifications

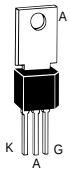
TYPE	Part Number	I_T		V_{DRM} & V_{RRM}	I_{GT}	I_{DRM} & I_{RRM}			V_{TM}	V_{GT}			I_H
	 TO-92	Maximum On-state Current (1)		Repetitive Peak Off-state Forward & Reverse Voltage	DC Gate Trigger Current (2) (11) (17)	Peak Off-state Current at V_{DRM} & V_{RRM} (19)			Peak On-state Voltage T_C = 25°C (3) (10)	DC Gate Trigger Voltage (4) (11)			DC Holding Current Initial On-state Current =20mAmps (5) (14) (18)
	See "Package Dimensions" section for variations.	Amps		Volts	µAmps	µAmps			Volts	Volts			mAmps
		RMS	AV			T_C = 25°C	T_C= 100°C	T_C = 125°C		T_C = - 65°C	T_C = 25°C	T_C = 100°C	
		MAX		MIN	MAX	MAX			MAX	MAX		MIN	MAX
0.8 Amp	EC103A	0.8	0.51	100	200	1.0	50		1.7	1.2	0.8	.25	5.0
	EC103B	0.8	0.51	200	200	1.0	50		1.7	1.2	0.8	.25	5.0
	EC103C	0.8	0.51	300	200	1.0	50		1.7	1.2	0.8	.25	5.0
	EC103D	0.8	0.51	400	200	1.0	50		1.7	1.2	0.8	.25	5.0
	EC103E	0.8	0.51	500	200	1.0	50		1.7	1.2	0.8	.25	5.0
	EC103M	0.8	0.51	600	200	2.0	100		1.7	1.2	0.8	.25	5.0
	EC103A1	0.8	0.51	100	12	1.0	50		1.7	1.2	0.8	0.2	5.0
	EC103B1	0.8	0.51	200	12	1.0	50		1.7	1.2	0.8	0.2	5.0
	EC103C1	0.8	0.51	300	12	1.0	50		1.7	1.2	0.8	0.2	5.0
	EC103D1	0.8	0.51	400	12	1.0	50		1.7	1.2	0.8	0.2	5.0
	EC103E1	0.8	0.51	500	12	1.0	50		1.7	1.2	0.8	0.2	5.0
	EC103M1	0.8	0.51	600	12	2.0	100		1.7	1.2	0.8	0.2	5.0
	EC103A2	0.8	0.51	100	50	1.0	50		1.7	1.2	0.8	.25	5.0
	EC103B2	0.8	0.51	200	50	1.0	50		1.7	1.2	0.8	.25	5.0
	EC103C2	0.8	0.51	300	50	1.0	50		1.7	1.2	0.8	.25	5.0
	EC103D2	0.8	0.51	400	50	1.0	50		1.7	1.2	0.8	.25	5.0
	EC103E2	0.8	0.51	500	50	1.0	50		1.7	1.2	0.8	.25	5.0
	EC103M2	0.8	0.51	600	50	2.0	100		1.7	1.2	0.8	.25	5.0
	EC103A3	0.8	0.51	100	500	1.0	50		1.7	1.2	0.8	.25	8.0
	EC103B3	0.8	0.51	200	500	1.0	50		1.7	1.2	0.8	.25	8.0
	EC103C3	0.8	0.51	300	500	1.0	50		1.7	1.2	0.8	.25	8.0
	EC103D3	0.8	0.51	400	500	1.0	50		1.7	1.2	0.8	.25	8.0
	EC103E3	0.8	0.51	500	500	1.0	50		1.7	1.2	0.8	.25	8.0
	EC103M3	0.8	0.51	600	500	2.0	100		1.7	1.2	0.8	.25	8.0
	EC113A	0.8	0.51	100	200	2.0	100		1.7	1.2	0.8	.25	15.0
	EC113B	0.8	0.51	200	200	2.0	100		1.7	1.2	0.8	.25	15.0
	EC113C	0.8	0.51	300	200	2.0	100		1.7	1.2	0.8	.25	15.0
	EC113D	0.8	0.51	400	200	2.0	100		1.7	1.2	0.8	.25	15.0
	EC113E	0.8	0.51	500	200	2.0	100		1.7	1.2	0.8	.25	15.0
	EC113M	0.8	0.51	600	200	2.0	100		1.7	1.2	0.8	.25	15.0
	EC113A3	0.8	0.51	100	500	2.0	100		1.7	1.2	0.8	.25	15.0
	EC113B3	0.8	0.51	200	500	2.0	100		1.7	1.2	0.8	.25	15.0
	EC113C3	0.8	0.51	300	500	2.0	100		1.7	1.2	0.8	.25	15.0
	EC113D3	0.8	0.51	400	500	2.0	100		1.7	1.2	0.8	.25	15.0
	EC113E3	0.8	0.51	500	500	2.0	100		1.7	1.2	0.8	.25	15.0
	EC113M3	0.8	0.51	600	500	2.0	100		1.7	1.2	0.8	.25	15.0
	2N5060	0.8	0.51	30	200	1.0		50	1.7	1.2	0.8	.25	5.0
	2N5061	0.8	0.51	60	200	1.0		50	1.7	1.2	0.8	.25	5.0
	2N5062	0.8	0.51	100	200	1.0		50	1.7	1.2	0.8	.25	5.0
	2N5063	0.8	0.51	150	200	1.0		50	1.7	1.2	0.8	.25	5.0
	2N5064	0.8	0.51	200	200	1.0		50	1.7	1.2	0.8	.25	5.0
	2N6564	0.8	0.51	300	200	1.0		100	1.7	1.2	0.8	.25	5.0
	2N6565	0.8	0.51	400	200	1.0		100	1.7	1.2	0.8	.25	5.0
1.5 AMPS	TCR22-2	1.5	.95	50	200	1.0	50	100	1.5	1.0	0.8	.25	5.0
	TCR22-3	1.5	.95	100	200	1.0	50	100	1.5	1.0	0.8	.25	5.0
	TCR22-4	1.5	.95	200	200	1.0	50	100	1.5	1.0	0.8	.25	5.0
	TCR22-6	1.5	.95	400	200	1.0	50	100	1.5	1.0	0.8	.25	5.0
	TCR22-8	1.5	.95	600	200	2.0	100	200	1.5	1.0	0.8	.25	5.0

See General Notes and Electrical Specifications Notes on page 5-4.

I_{GM}	V_{GRM}	P_{GM}	$P_{G(AV)}$	I_{TSM}		dv/dt	di/dt	t_{gt}	t_q	I^2t
Peak Gate Current (16)	Peak Reverse Gate Voltage	Peak Gate Power Dissipation (16)	Average Gate Power Dissipation	Peak One Cycle Surge Forward Current (6) (7) (12)		Critical Rate-Of-Rise Of Forward Off-State Voltage	Maximum Rate-Of-Change Of On-State Current I_{GT} = 50mA With 0.1µs Rise Time	Gate Controlled Turn-On Time Gate Pulse = 10mA Min. Width = 15µs With Rise Time ≤ 0.1 µs (8)	Circuit Commutated Turn-Off Time (9)	RMS Surge (Non-Repetitive) On-State Current For A Period Of 8.3ms For Fusing
				Amps						
Amps	Volts	Watts	Watts	60Hz	50Hz	Volts/µSec	Amps/µSec	µSec	µSec	$Amps^2$/Sec
	MIN					MIN		TYP	MAX	
1.0	5.0	1.0	0.1	20	16	30	50	3.5	50	1.6
1.0	5.0	1.0	0.1	20	16	30	50	3.5	50	1.6
1.0	5.0	1.0	0.1	20	16	30	50	3.5	50	1.6
1.0	5.0	1.0	0.1	20	16	30	50	3.5	50	1.6
1.0	5.0	1.0	0.1	20	16	20	50	3.5	50	1.6
1.0	5.0	1.0	0.1	20	16	15	50	3.5	50	1.6
1.0	5.0	1.0	0.1	20	16	20	50	2.0	60	1.6
1.0	5.0	1.0	0.1	20	16	20	50	2.0	60	1.6
1.0	5.0	1.0	0.1	20	16	20	50	2.0	60	1.6
1.0	5.0	1.0	0.1	20	16	20	50	2.0	60	1.6
1.0	5.0	1.0	0.1	20	16	15	50	2.0	60	1.6
1.0	5.0	1.0	0.1	20	16	10	50	2.0	60	1.6
1.0	5.0	1.0	0.1	20	16	25	50	3.0	60	1.6
1.0	5.0	1.0	0.1	20	16	25	50	3.0	60	1.6
1.0	5.0	1.0	0.1	20	16	25	50	3.0	60	1.6
1.0	5.0	1.0	0.1	20	16	25	50	3.0	60	1.6
1.0	5.0	1.0	0.1	20	16	20	50	3.0	60	1.6
1.0	5.0	1.0	0.1	20	16	10	50	3.0	60	1.6
1.0	5.0	1.0	0.1	20	16	40	50	5.0	45	1.6
1.0	5.0	1.0	0.1	20	16	40	50	5.0	45	1.6
1.0	5.0	1.0	0.1	20	16	40	50	5.0	45	1.6
1.0	5.0	1.0	0.1	20	16	40	50	5.0	45	1.6
1.0	5.0	1.0	0.1	20	16	30	50	5.0	45	1.6
1.0	5.0	1.0	0.1	20	16	20	50	5.0	45	1.6
1.0	5.0	1.0	0.1	20	16	30	50	4.0	30	1.6
1.0	5.0	1.0	0.1	20	16	30	50	4.0	30	1.6
1.0	5.0	1.0	0.1	20	16	30	50	4.0	30	1.6
1.0	5.0	1.0	0.1	20	16	30	50	4.0	30	1.6
1.0	5.0	1.0	0.1	20	16	20	50	4.0	30	1.6
1.0	5.0	1.0	0.1	20	16	15	50	4.0	30	1.6
1.0	5.0	1.0	0.1	20	16	40	50	5.0	18	1.6
1.0	5.0	1.0	0.1	20	16	40	50	5.0	18	1.6
1.0	5.0	1.0	0.1	20	16	40	50	5.0	18	1.6
1.0	5.0	1.0	0.1	20	16	40	50	5.0	18	1.6
1.0	5.0	1.0	0.1	20	16	30	50	5.0	18	1.6
1.0	5.0	1.0	0.1	20	16	20	50	5.0	18	1.6
1.0	5.0	1.0	0.1	20	16	25	50	2.2	60	1.6
1.0	5.0	1.0	0.1	20	16	25	50	2.2	60	1.6
1.0	5.0	1.0	0.1	20	16	25	50	2.2	60	1.6
1.0	5.0	1.0	0.1	20	16	25	50	2.2	60	1.6
1.0	5.0	1.0	0.1	20	16	25	50	2.2	60	1.6
1.0	6.0	1.0	0.1	20	16	25	50	2.2	60	1.6
1.0	6.0	1.0	0.1	20	16	25	50	2.2	60	1.6
1.0	6.0	1.0	0.1	20	16	75	50	3.5	50	1.6
1.0	6.0	1.0	0.1	20	16	75	50	3.5	50	1.6
1.0	6.0	1.0	0.1	20	16	60	50	3.5	50	1.6
1.0	6.0	1.0	0.1	20	16	40	50	3.5	50	1.6
1.0	6.0	1.0	0.1	20	16	30	50	3.5	50	1.6

See General Notes and Electrical Specifications Notes on page 5-4.

Electrical Specifications

TYPE	Part Number	I_T		V_{DRM} & V_{RRM}	I_{GT}	I_{DRM} & I_{RRM}		V_{TM}	V_{GT}			I_H	I_{GM}
	Non-Isolated	Maximum On-State Current (1)		Repetitive Peak Off-State Forward & Reverse Voltage	DC Gate Trigger Current (2) (11) (13)	Peak Off-State Current at V_{DRM} & V_{RRM} (19)		Peak On-State Voltage T_C = 25°C (3) (10)	DC Gate Trigger Voltage (4) (11)			DC Holding Current Initial On-State Current = 20mA (5) (15) (18)	Peak Gate Current (16)
	 TO-202AB	Amps		Volts	µAmps	µAmps		Volts	Volts			mAmps	
	See "Package Dimensions" section for variations.	$I_{T(RMS)}$	$I_{T(AV)}$			T_C = 25°C	T_C = 110°C		T_C = - 40°C	T_C = 25°C	T_C = 110°C	T_C = 25°C	Amps
		MAX	MAX	MIN	MAX	MAX	MAX	MAX	MAX	MAX	MIN	MAX	
4.0 Amps	**T106F1**	**4.0**	**2.5**	**50**	**200**	**2.0**	**100**	**2.2**	**1.0**	**0.8**	**0.2**	**5.0**	**1.0**
	T106A1	**4.0**	**2.5**	**100**	**200**	**2.0**	**100**	**2.2**	**1.0**	**0.8**	**0.2**	**5.0**	**1.0**
	T106B1	**4.0**	**2.5**	**200**	**200**	**2.0**	**100**	**2.2**	**1.0**	**0.8**	**0.2**	**5.0**	**1.0**
	T106C1	**4.0**	**2.5**	**300**	**200**	**2.0**	**100**	**2.2**	**1.0**	**0.8**	**0.2**	**5.0**	**1.0**
	T106D1	**4.0**	**2.5**	**400**	**200**	**2.0**	**100**	**2.2**	**1.0**	**0.8**	**0.2**	**5.0**	**1.0**
	T106E1	**4.0**	**2.5**	**500**	**200**	**2.0**	**100**	**2.2**	**1.0**	**0.8**	**0.2**	**5.0**	**1.0**
	T106M1	**4.0**	**2.5**	**600**	**200**	**2.0**	**100**	**2.2**	**1.0**	**0.8**	**0.2**	**5.0**	**1.0**
	T107F1	**4.0**	**2.5**	**50**	**500**	**2.0**	**100**	**2.5**	**1.0**	**0.8**	**0.2**	**6.0**	**1.0**
	T107A1	**4.0**	**2.5**	**100**	**500**	**2.0**	**100**	**2.5**	**1.0**	**0.8**	**0.2**	**6.0**	**1.0**
	T107B1	**4.0**	**2.5**	**200**	**500**	**2.0**	**100**	**2.5**	**1.0**	**0.8**	**0.2**	**6.0**	**1.0**
	T107C1	**4.0**	**2.5**	**300**	**500**	**2.0**	**100**	**2.5**	**1.0**	**0.8**	**0.2**	**6.0**	**1.0**
	T107D1	**4.0**	**2.5**	**400**	**500**	**2.0**	**100**	**2.5**	**1.0**	**0.8**	**0.2**	**6.0**	**1.0**
	T107E1	**4.0**	**2.5**	**500**	**500**	**2.0**	**100**	**2.5**	**1.0**	**0.8**	**0.2**	**6.0**	**1.0**
	T107M1	**4.0**	**2.5**	**600**	**500**	**2.0**	**100**	**2.5**	**1.0**	**0.8**	**0.2**	**6.0**	**1.0**

General Notes

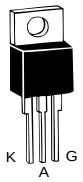
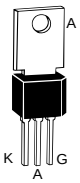
- Teccor 2N5060 and 2N6564 Series devices conform to all JEDEC registered data. See specifications table on page 5-2.
- The case temperature (TC) is measured as shown on dimensional outline drawings. See "Package Dimensions" section of this catalog.
- All measurements (except I_{GT}) are made with an external resistor R_{GK} = 1kΩ unless otherwise noted.
- All measurements are made at 60Hz with a resistive load at an ambient temperature of +25°C unless otherwise specified.
- Operating temperature (T_J) is -65°C to + 110°C for "EC" Series devices; -65°C to +125°C for "2N" Series devices; -40°C to +125°C for "TCR" Series; and -40°C to +110°C for all others.
- Storage temperature range (T_S) is -65°C to + 150°C for TO-92 devices; -40°C to +150°C for TO-202 devices; and -40°C to +125°C for all others.
- Lead solder temperature is a maximum of +230°C for 10 seconds maximum ≥ 1/16" (1.59mm) from case.

Electrical Specification Notes

(1) See Figures 5.1 through 5.9 for current ratings at specified operating case temperatures.
(2) See Figure 5.10 for I_{GT} vs T_C.
(3) See Figure 5.11 for instantaneous on-state current (i_T) vs on-state voltage (v_T) - (typical).
(4) See Figure 5.12 for V_{GT} vs T_C.
(5) See Figure 5.13 for I_H vs T_C.
(6) For more than one full cycle, see Figure 5.14.
(7) 0.8 - 4.0A devices also have a pulse peak forward current on-state rating (repetitive) of 75A. This rating applies for operation at 60Hz, 75°C maximum tab (or anode) lead temperature, switching from 80V peak, sinusoidal current pulse width of 10µs minimum, 15µs maximum. See Figures 5.20 and 5.21.
(8) See Figure 5.15 for t_{gt} vs I_{GT}.
(9) Test conditions as follows:
$T_C \leq 80°C$, rectangular current waveform; rate-of-rise of current ≤ 10A/µs. Rate-of-reversal of current ≤ 5A/µs. I_{TM} = 1A (50µs pulse) Repetition Rate = 60pps. V_{RRM} = Rated. V_R = 15V minimum, V_{DRM} = Rated. Rate-of-rise reapplied forward blocking voltage = 5V/µs. Gate Bias = 0V, 100Ω (during turn-off time interval).
(10) Test condition is maximum rated RMS current except TO-92 devices are $1.2A_{PK}$; T106/T107 devices are $4A_{PK}$.
(11) V_D = 6VDC, R_L = 100Ω. See Figure 5.19 for simple test circuit for measuring gate trigger voltage and gate trigger current.
(12) See Figures 5.1 through 5.9 for maximum allowable case temperature at maximum rated current.
(13) I_{GT} = 500µA maximum for T_C = -40°C for T106 devices.
(14) I_H = 10mA maximum for T_C = -65°C for 2N5060 Series and 2N6564 Series devices.
(15) I_H = 6mA maximum for T_C = -40°C for T106 devices.
(16) Pulse Width ≤ 10µs.
(17) I_{GT} = 350µA maximum at T_C = -65°C for 2N5060 Series and 2N6564 Series devices.
(18) Latching current can be higher than 20mA for higher I_{GT} types. Also latching current can be much higher at -40°C. See Figure 5.18.
(19) $T_C = T_J$ for test conditions in off-state.

V_{GRM}	P_{GM}	$P_{G(AV)}$	I_{TSM}		dv/dt	di/dt	t_{gt}	t_q	I^2t
Peak Reverse Gate Voltage	Peak Gate Power Dissipation (16)	Average Gate Power Dissipation	Peak One Cycle Surge Forward Current (6) (7) (12) Amps		Critical Rate-Of-Rise Of Forward Off-State Voltage Volts/µSec	Maximum Rate-Of-Change Of On-State Current I_{GT} = 50mA with 0.1µs Rise Time	Gate Controlled Turn-On Time Gate Pulse = 10mA Min. Width = 15µs with Rise Time ≤ 0.1 µs (8)	Circuit Commutated Turn-Off Time (9)	RMS Surge (Non-Repetitive) On-State Current For A Period Of 8.3 msec for Fusing
Volts	Watts	Watts	60Hz	50Hz	T_C = 110°C	Amps/µSec	µSec	µSec	$Amps^2Sec$
MIN					TYP		TYP	MAX	
6.0	**1.0**	**0.1**	**20**	**16**	**8**	**50**	**4.0**	**50**	**1.6**
6.0	**1.0**	**0.1**	**20**	**16**	**8**	**50**	**4.0**	**50**	**1.6**
6.0	**1.0**	**0.1**	**20**	**16**	**8**	**50**	**4.0**	**50**	**1.6**
6.0	**1.0**	**0.1**	**20**	**16**	**8**	**50**	**4.0**	**50**	**1.6**
6.0	**1.0**	**0.1**	**20**	**16**	**8**	**50**	**4.0**	**50**	**1.6**
6.0	**1.0**	**0.1**	**20**	**16**	**8**	**50**	**4.0**	**50**	**1.6**
6.0	**1.0**	**0.1**	**20**	**16**	**8**	**50**	**4.0**	**50**	**1.6**
6.0	**1.0**	**0.1**	**20**	**16**	**8**	**50**	**5.0**	**45**	**1.6**
6.0	**1.0**	**0.1**	**20**	**16**	**8**	**50**	**5.0**	**45**	**1.6**
6.0	**1.0**	**0.1**	**20**	**16**	**8**	**50**	**5.0**	**45**	**1.6**
6.0	**1.0**	**0.1**	**20**	**16**	**8**	**50**	**5.0**	**45**	**1.6**
6.0	**1.0**	**0.1**	**20**	**16**	**8**	**50**	**5.0**	**45**	**1.6**
6.0	**1.0**	**0.1**	**20**	**16**	**8**	**50**	**5.0**	**45**	**1.6**
6.0	**1.0**	**0.1**	**20**	**16**	**8**	**50**	**5.0**	**45**	**1.6**

Electrical Specifications

TYPE	Part Number		I_T		V_{DRM} & V_{RRM}	I_{GT}	I_{DRM} & I_{RRM}		V_{TM}	V_{GT}			I_H
	Isolated	Non-Isolated	Maximum On-State Current (1)		Repetitive Peak Off-State Forward & Reverse Voltage	DC Gate Trigger Current (2) (11)	Peak Off-State Current at V_{DRM} & V_{RRM} (19)		Peak On-State Voltage T_C = 25°C (3) (10)	DC Gate Trigger Voltage (4) (11)			DC Holding Current Initial On-State Current = 20mA (5) (18)
	 TO-220AB	 TO-202AB	Amps		Volts	µAmps	mAmps		Volts	Volts			mAmps
	See "Package Dimensions" section for variations.		$I_{T(RMS)}$	$I_{T(AV)}$			T_C = 25°C	T_C = 110°C		T_C = - 40°C	T_C = 25°C	T_C = 110°C	
			MAX	MAX	MIN	MAX	MAX	MAX	MAX	MAX	MAX	MIN	MAX
6.0 Amps	S0506LS2	S0506FS21	6.0	3.8	50	200	.005	0.25	1.6	1.0	0.8	.25	6.0
	S0506LS3	S0506FS31	6.0	3.8	50	500	.005	0.25	1.6	1.0	0.8	.25	8.0
	S1006LS2	S1006FS21	6.0	3.8	100	200	.005	0.25	1.6	1.0	0.8	.25	6.0
	S1006LS3	S1006FS31	6.0	3.8	100	500	.005	0.25	1.6	1.0	0.8	.25	8.0
	S2006LS2	S2006FS21	6.0	3.8	200	200	.005	0.25	1.6	1.0	0.8	.25	6.0
	S2006LS3	S2006FS31	6.0	3.8	200	500	.005	0.25	1.6	1.0	0.8	.25	8.0
	S4006LS2	S4006FS21	6.0	3.8	400	200	.005	0.25	1.6	1.0	0.8	.25	6.0
	S4006LS3	S4006FS31	6.0	3.8	400	500	.005	0.25	1.6	1.0	0.8	.25	8.0
	S6006LS2	S6006FS21	6.0	3.8	600	200	.005	0.25	1.6	1.0	0.8	.25	6.0
	S6006LS3	S6006FS31	6.0	3.8	600	500	.005	0.25	1.6	1.0	0.8	.25	8.0
8.0 Amps	S0508LS2	S0508FS21	8.0	5.1	50	200	.005	0.25	1.6	1.0	0.8	.25	6.0
	S0508LS3	S0508FS31	8.0	5.1	50	500	.005	0.25	1.6	1.0	0.8	.25	8.0
	S1008LS2	S1008FS21	8.0	5.1	100	200	.005	0.25	1.6	1.0	0.8	.25	6.0
	S1008LS3	S1008FS31	8.0	5.1	100	500	.005	0.25	1.6	1.0	0.8	.25	8.0
	S2008LS2	S2008FS21	8.0	5.1	200	200	.005	0.25	1.6	1.0	0.8	.25	6.0
	S2008LS3	S2008FS31	8.0	5.1	200	500	.005	0.25	1.6	1.0	0.8	.25	8.0
	S4008LS2	S4008FS21	8.0	5.1	400	200	.005	0.25	1.6	1.0	0.8	.25	6.0
	S4008LS3	S4008FS31	8.0	5.1	400	500	.005	0.25	1.6	1.0	0.8	.25	8.0
	S6008LS2	S6008FS21	8.0	5.1	600	200	.005	0.25	1.6	1.0	0.8	.25	6.0
	S6008LS3	S6008FS31	8.0	5.1	600	500	.005	0.25	1.6	1.0	0.8	.25	8.0
10.0 Amps	S0510LS2	S0510FS21	10.0	6.4	50	200	.005	0.25	1.6	1.0	0.8	.25	6.0
	S0510LS3	S0510FS31	10.0	6.4	50	500	.005	0.25	1.6	1.0	0.8	.25	8.0
	S1010LS2	S1010FS21	10.0	6.4	100	200	.005	0.25	1.6	1.0	0.8	.25	6.0
	S1010LS3	S1010FS31	10.0	6.4	100	500	.005	0.25	1.6	1.0	0.8	.25	8.0
	S2010LS2	S2010FS21	10.0	6.4	200	200	.005	0.25	1.6	1.0	0.8	.25	6.0
	S2010LS3	S2010FS31	10.0	6.4	200	500	.005	0.25	1.6	1.0	0.8	.25	8.0
	S4010LS2	S4010FS21	10.0	6.4	400	200	.005	0.25	1.6	1.0	0.8	.25	6.0
	S4010LS3	S4010FS31	10.0	6.4	400	500	.005	0.25	1.6	1.0	0.8	.26	8.0
	S6010LS2	S6010FS21	10.0	6.4	600	200	.005	0.25	1.6	1.0	0.8	.25	6.0
	S6010LS3	S6010FS31	10.0	6.4	600	500	.005	0.25	1.6	1.0	0.8	.25	8.0

General Notes

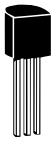
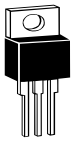
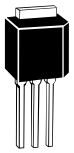
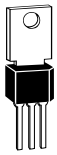
- Teccor 2N5060 and 2N6564 Series devices conform to all JEDEC registered data. See specifications table on page 5-2.
- The case temperature (TC) is measured as shown on dimensional outline drawings. See "Package Dimensions" section of this catalog.
- All measurements (except I_{GT}) are made with an external resistor R_{GK} = 1kΩ unless otherwise noted.
- All measurements are made at 60Hz with a resistive load at an ambient temperature of +25°C unless otherwise specified.
- Operating temperature (T_J) is -65°C to + 110°C for "EC" Series devices; -65°C to +125°C for "2N" Series devices; -40°C to +125°C for "TCR" Series; and -40°C to +110°C for all others.
- Storage temperature range (T_S) is -65°C to + 150°C for TO-92 devices; -40°C to +150°C for TO-202 devices; and -40°C to +125°C for all others.
- Lead solder temperature is a maximum of +230°C for 10 seconds maximum ≥ 1/16" (1.59mm) from case.

I_{GM}	V_{GRM}	P_{GM}	$P_{G(AV)}$	I_{TSM}		dv/dt	di/dt	t_{gt}	t_q	I^2t
Peak Gate Current (16)	Peak Reverse Gate Voltage	Peak Gate Power Dissipation (16)	Average Gate Power Dissipation	Peak One Cycle Surge Forward Current (6) (12)		Critical Rate-Of-Rise Of Forward Off-State Voltage Volts/µSec	Maximum Rate-Of-Change Of On-State Current I_{GT} = 50mA With 0.1 µs Rise Time	Gate Controlled Turn-On Time Gate Pulse = 10mA Min. Width = 15µs With Rise Time ≤ 0.1 µs (8)	Circuit Commutated Turn-Off Time (9)	RMS Surge (Non-Repetitive) On-State Current For A Period Of 8.3 mSec For Fusing
Amps	Volts	Watts	Watts	Amps		T_C = 110°C	Amps/ µSec	µSec	µSec	$Amps^2Sec$
	MIN			60 Hz	50 Hz	TYP		TYP	MAX	
1.0	**6.0**	**1.0**	**0.1**	**100**	**83**	**20**	**100**	**4.0**	**50**	**41**
1.0	**6.0**	**1.0**	**0.1**	**100**	**83**	**20**	**100**	**5.0**	**45**	**41**
1.0	**6.0**	**1.0**	**0.1**	**100**	**83**	**10**	**100**	**4.0**	**50**	**41**
1.0	**6.0**	**1.0**	**0.1**	**100**	**83**	**10**	**100**	**5.0**	**45**	**41**
1.0	**6.0**	**1.0**	**0.1**	**100**	**83**	**10**	**100**	**4.0**	**50**	**41**
1.0	**6.0**	**1.0**	**0.1**	**100**	**83**	**10**	**100**	**5.0**	**45**	**41**
1.0	**6.0**	**1.0**	**0.1**	**100**	**83**	**5**	**100**	**4.0**	**50**	**41**
1.0	**6.0**	**1.0**	**0.1**	**100**	**83**	**5**	**100**	**5.0**	**45**	**41**
1.0	**6.0**	**1.0**	**0.1**	**100**	**83**	**5**	**100**	**4.0**	**50**	**41**
1.0	**6.0**	**1.0**	**0.1**	**100**	**83**	**5**	**100**	**5.0**	**45**	**41**
1.0	**6.0**	**1.0**	**0.1**	**100**	**83**	**20**	**100**	**4.0**	**50**	**41**
1.0	**6.0**	**1.0**	**0.1**	**100**	**83**	**20**	**100**	**5.0**	**45**	**41**
1.0	**6.0**	**1.0**	**0.1**	**100**	**83**	**10**	**100**	**4.0**	**50**	**41**
1.0	**6.0**	**1.0**	**0.1**	**100**	**83**	**10**	**100**	**5.0**	**45**	**41**
1.0	**6.0**	**1.0**	**0.1**	**100**	**83**	**10**	**100**	**4.0**	**50**	**41**
1.0	**6.0**	**1.0**	**0.1**	**100**	**83**	**10**	**100**	**5.0**	**45**	**41**
1.0	**6.0**	**1.0**	**0.1**	**100**	**83**	**5**	**100**	**4.0**	**50**	**41**
1.0	**6.0**	**1.0**	**0.1**	**100**	**83**	**5**	**100**	**5.0**	**45**	**41**
1.0	**6.0**	**1.0**	**0.1**	**100**	**83**	**5**	**100**	**4.0**	**50**	**41**
1.0	**6.0**	**1.0**	**0.1**	**100**	**83**	**5**	**100**	**5.0**	**45**	**41**
1.0	**6.0**	**1.0**	**0.1**	**100**	**83**	**20**	**100**	**4.0**	**50**	**41**
1.0	**6.0**	**1.0**	**0.1**	**100**	**83**	**20**	**100**	**5.0**	**45**	**41**
1.0	**6.0**	**1.0**	**0.1**	**100**	**83**	**10**	**100**	**4.0**	**50**	**41**
1.0	**6.0**	**1.0**	**0.1**	**100**	**83**	**10**	**100**	**5.0**	**45**	**41**
1.0	**6.0**	**1.0**	**0.1**	**100**	**83**	**10**	**100**	**4.0**	**50**	**41**
1.0	**6.0**	**1.0**	**0.1**	**100**	**83**	**10**	**100**	**5.0**	**45**	**41**
1.0	**6.0**	**1.0**	**0.1**	**100**	**83**	**5**	**100**	**4.0**	**50**	**41**
1.0	**6.0**	**1.0**	**0.1**	**100**	**83**	**5**	**100**	**5.0**	**45**	**41**
1.0	**6.0**	**1.0**	**0.1**	**100**	**83**	**5**	**100**	**4.0**	**50**	**41**
1.0	**6.0**	**1.0**	**0.1**	**100**	**83**	**5**	**100**	**5.0**	**45**	**41**

Electrical Specification Notes

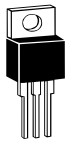
(1) See Figures 5.1 through 5.9 for current ratings at specified operating case temperatures.
(2) See Figure 5.10 for I_{GT} vs T_C.
(3) See Figure 5.11 for instantaneous on-state current (i_T) vs on-state voltage (v_T) - (typical).
(4) See Figure 5.12 for V_{GT} vs T_C.
(5) See Figure 5.13 for I_H vs T_C.
(6) For more than one full cycle, see Figure 5.14.
(7) 0.8 - 4.0A devices also have a pulse peak forward current on-state rating (repetitive) of 75A. This rating applies for operation at 60Hz, 75°C maximum tab (or anode) lead temperature, switching from 80V peak, sinusoidal current pulse width of 10µs minimum, 15µs maximum. See Figures 5.20 and 5.21.
(8) See Figure 5.15 for t_{gt} vs I_{GT}.
(9) Test conditions as follows:
$T_C \leq$ 80°C, rectangular current waveform; rate-of-rise of current $\leq$ 10A/µs. Rate-of-reversal of current $\leq$ 5A/µs. I_{TM} = 1A (50µs pulse) Repetition Rate = 60pps. V_{RRM} = Rated.
V_R = 15V minimum, V_{DRM} = Rated. Rate-of-rise reapplied forward blocking voltage= 5V/µs. Gate Bias = 0V, 100Ω (during turn-off time interval).
(10) Test condition is maximum rated RMS current except TO-92 devices are $1.2A_{PK}$; T106/T107 devices are $4A_{PK}$.
(11) V_D = 6VDC, R_L = 100Ω. See Figure 5.19 for simple test circuit for measuring gate trigger voltage and gate trigger current.
(12) See Figures 5.1 through 5.9 for maximum allowable case temperature at maximum rated current.
(13) I_{GT} = 500µA maximum for T_C = -40°C for T106 devices.
(14) I_H = 10mA maximum for T_C = -65°C for 2N5060 Series and 2N6564 Series devices.
(15) I_H = 6mA maximum for T_C = -40°C for T106 devices.
(16) Pulse Width ≤ 10µs.
(17) I_{GT} = 350µA maximum at T_C = -65°C for 2N5060 Series and 2N6564 Series devices.
(18) Latching current can be higher than 20mA for higher I_{GT} types. Also latching current can be much higher at -40°C. See Figure 5.18.
(19) T_C = T_J for test conditions in off-state.

Electrical Specifications

THERMAL RESISTANCE (STEADY STATE) $R_{\theta JC}$ [$R_{\theta JA}$] °C/W (TYPICAL)				
	E	L	F2	F
	 TO-92	 THERMOTAB TO-220AB	 TYPE 2 TO-202AB	 TYPE 1 & 3 TO-202AB
0.8 Amp	**75 [160]**			
1.5 Amps	**50 [160]**			
4.0 Amps			**10 [100]**	**6.2 [80]**
6.0 Amps		**4.0 [65]**		**4.3**
8.0 Amps		**3.4**		**3.9**
10.0 Amps		**3.0**		**3.4**

Electrical Isolation

Teccor's isolated sensitive SCRs will withstand a minimum high potential test of 2500 VAC RMS from leads to mounting tab over the device's operating temperature range. See table below for other standard and optional isolation ratings.

ELECTRICAL ISOLATION FROM LEADS TO MOUNTING TAB	
VAC(RMS)	 THERMOTAB** TO-220AB
2500	**Standard**
4000	**Optional***

*For 4000V Isolation use "V" Suffix in part number
**UL Recognized File #E71639

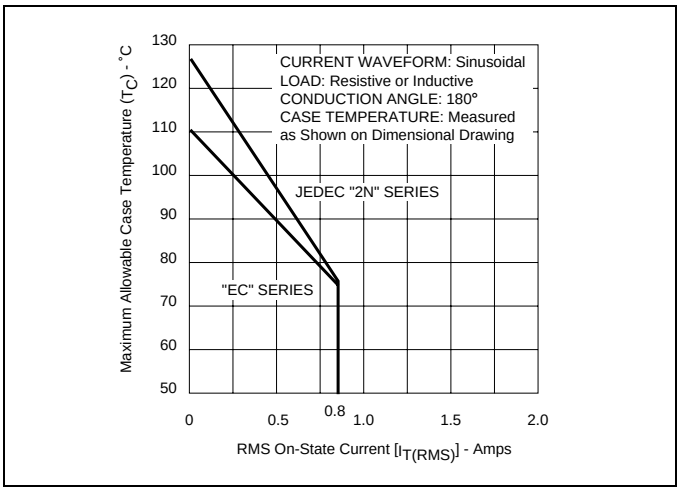


Figure 5.1 Maximum Allowable Case Temperature vs RMS On-State Current (JEDEC "2N" Series and "EC" Series)

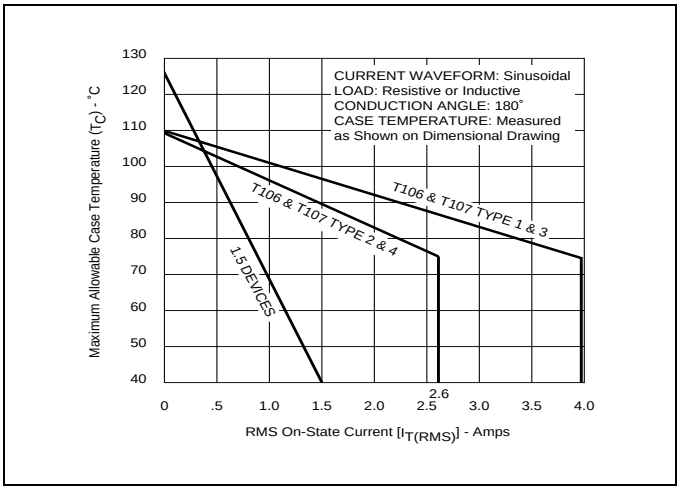


Figure 5.2 Maximum Allowable Case Temperature vs RMS On-State Current (T106 and T107)

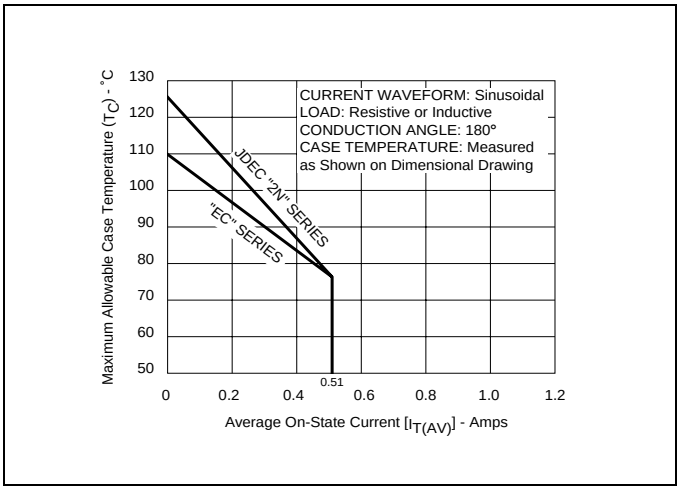


Figure 5.3 Maximum Allowable Case Temperature vs Average On-State Current (JEDEC "2N" Series and "EC" Series)

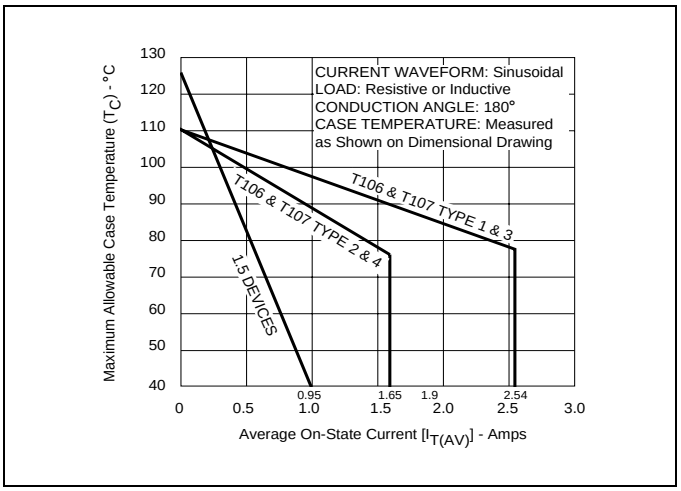


Figure 5.4 Maximum Allowable Case Temperature vs Average On-State Current (T106 and T107)

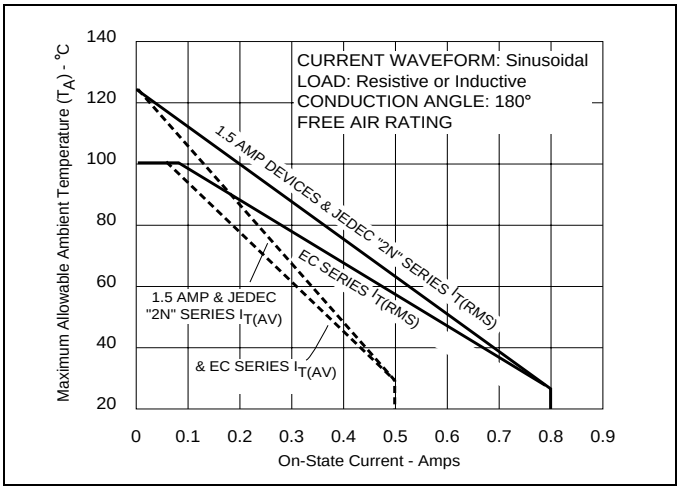


Figure 5.5 Maximum Allowable Ambient Temperature vs On-State Current (1.5 Amp, JEDEC “2N” Series and “EC” Series)

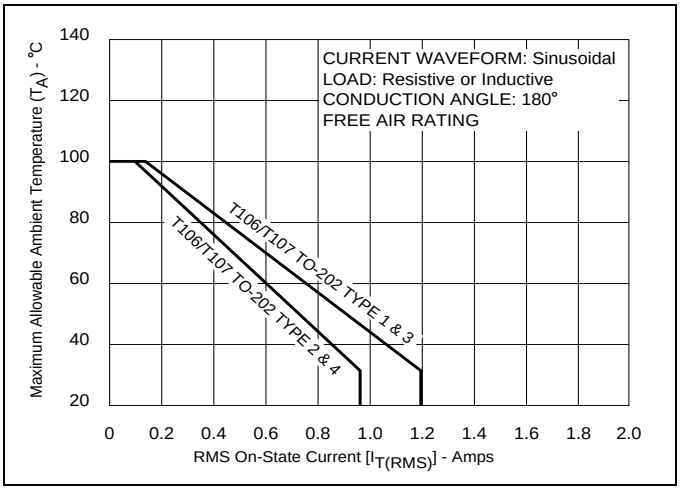


Figure 5.6 Maximum Allowable Ambient Temperature vs RMS On-State Current (T106 and T107)

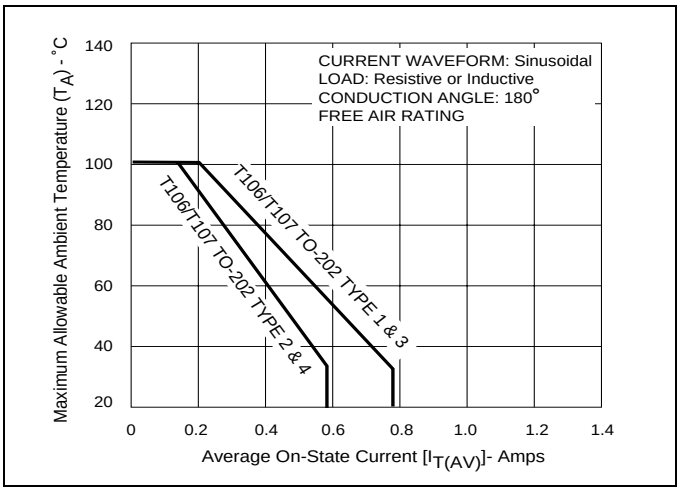


Figure 5.7 Maximum Allowable Ambient Temperature vs Average On-State Current

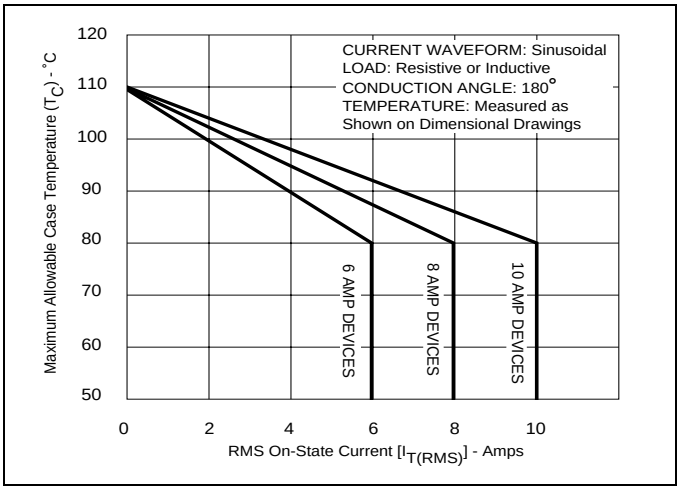


Figure 5.8 Maximum Allowable Case Temperature vs RMS On-State Current

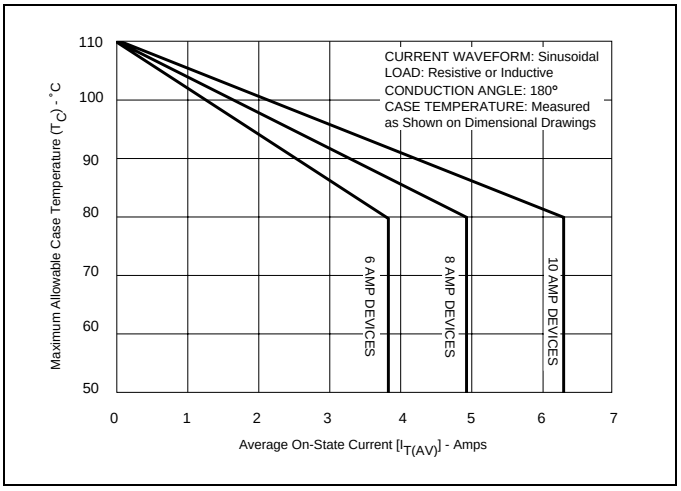


Figure 5.9 Maximum Allowable Case Temperature vs Average On-State Current

Electrical Specifications

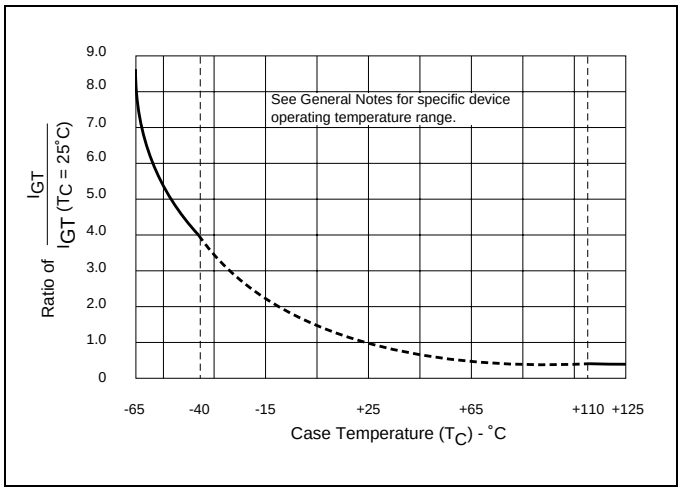


Figure 5.10 Normalized DC Gate-Trigger Current vs Case Temperature

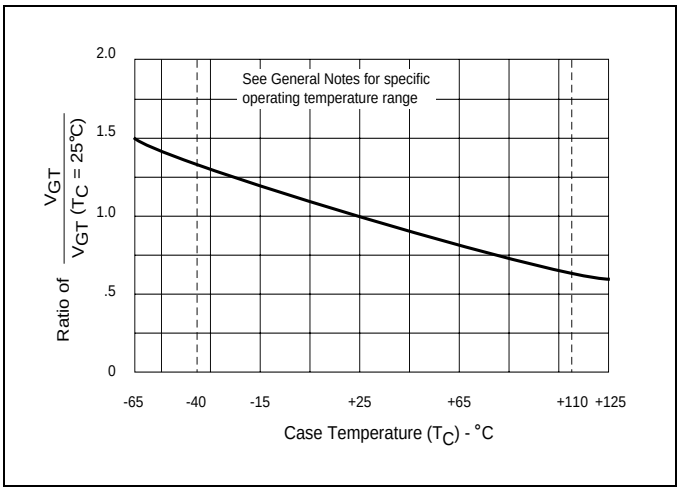


Figure 5.12 Normalized DC Gate-Trigger Voltage vs Case Temperature

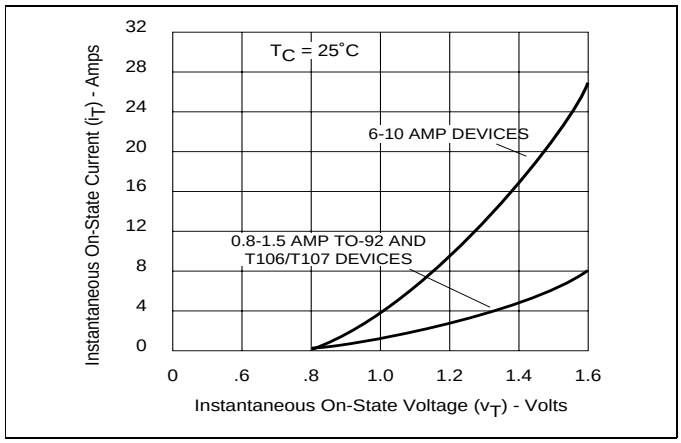


Figure 5.11 Instantaneous On-State Current vs On-State Voltage (Typical)

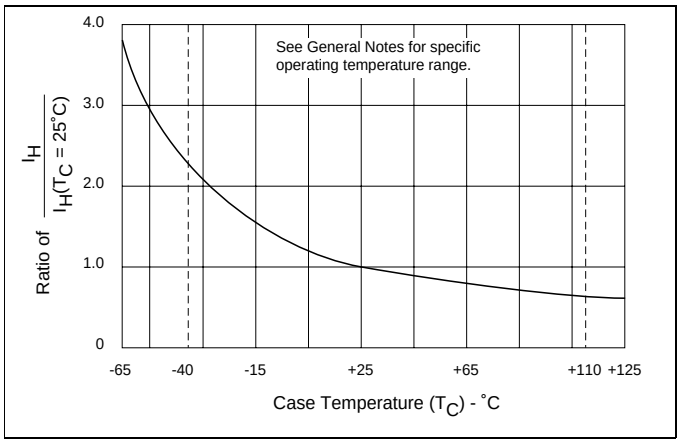


Figure 5.13 Normalized DC Holding Current vs Case Temperature

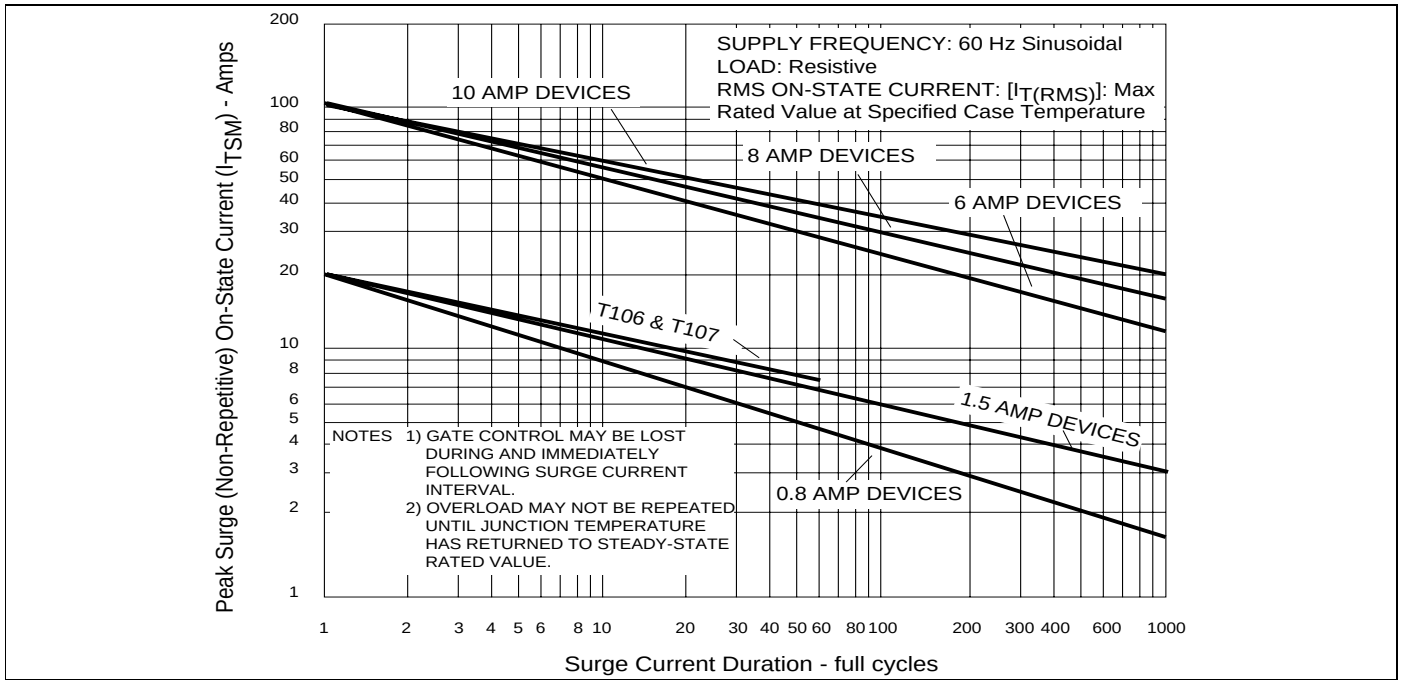


Figure 5.14 Peak Surge On-State Current vs Surge Current Duration

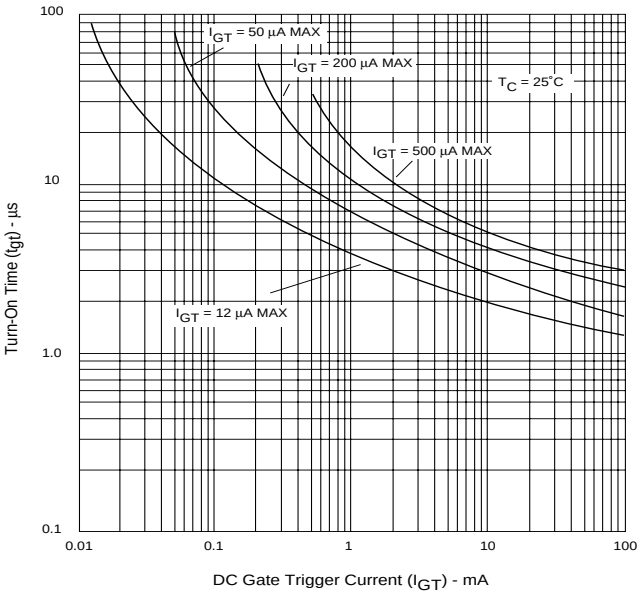


Figure 5.15 Typical Turn-On Time vs Gate Trigger Current

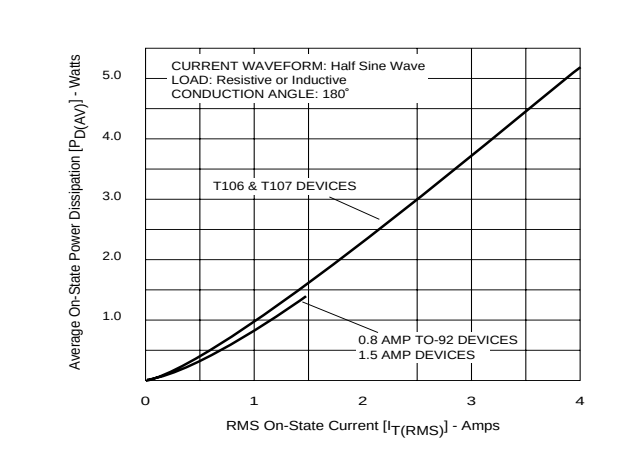


Figure 5.16 Power Dissipation (Typical) vs RMS On-State Current

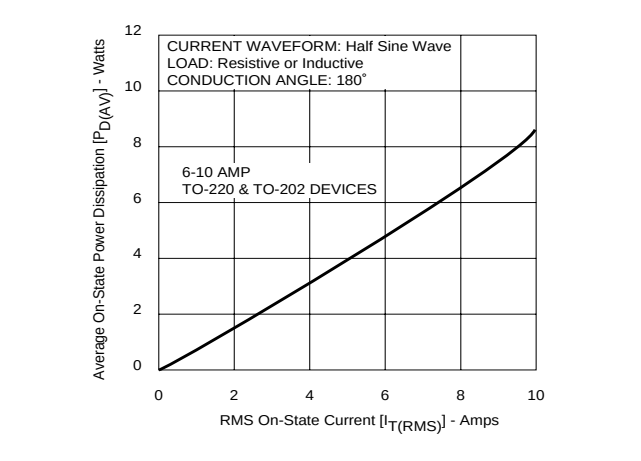


Figure 5.17 Power Dissipation (Typical) vs RMS On-State Current

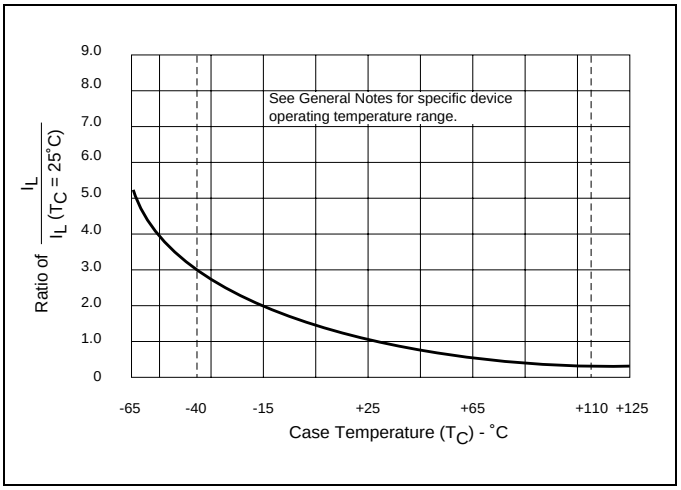


Figure 5.18 Normalized DC Latching Current vs Case Temperature

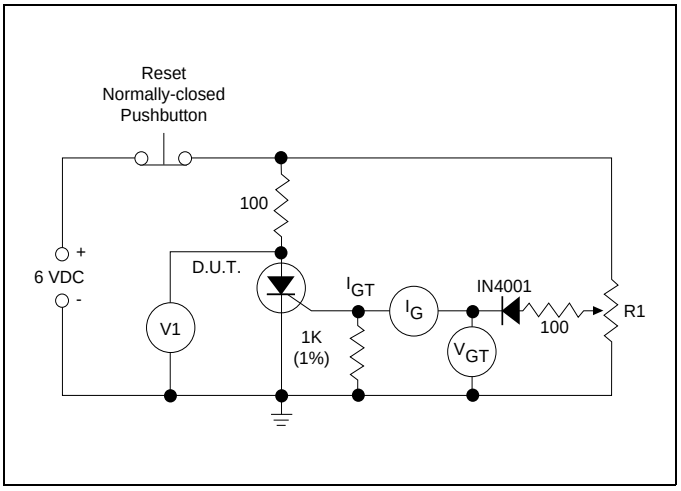


Figure 5.19 Simple Test Circuit For Gate Trigger Voltage and Current Measurement

Note: V1 — 0-10 volt DC meter
VGT — 0-1 volt DC meter
I_G — 0-1mA DC millimeter
R1 — 1K potentiometer

To measure gate trigger voltage and current, raise gate voltage (V_{GT}) until meter reading V1 drops from 6 volts to 1 volt. Gate trigger voltage is the reading on V_{GT} just prior to V1 dropping. Gate trigger current I_{GT} can be computed from the relationship:

$$I_{GT} = I_G - \frac{V_{GT}}{1000} Amps$$

where I_G is reading (in amps) on meter just prior to V1 dropping.

Note: I_{GT} may turn out to be a negative quantity (trigger current flows out from gate lead).

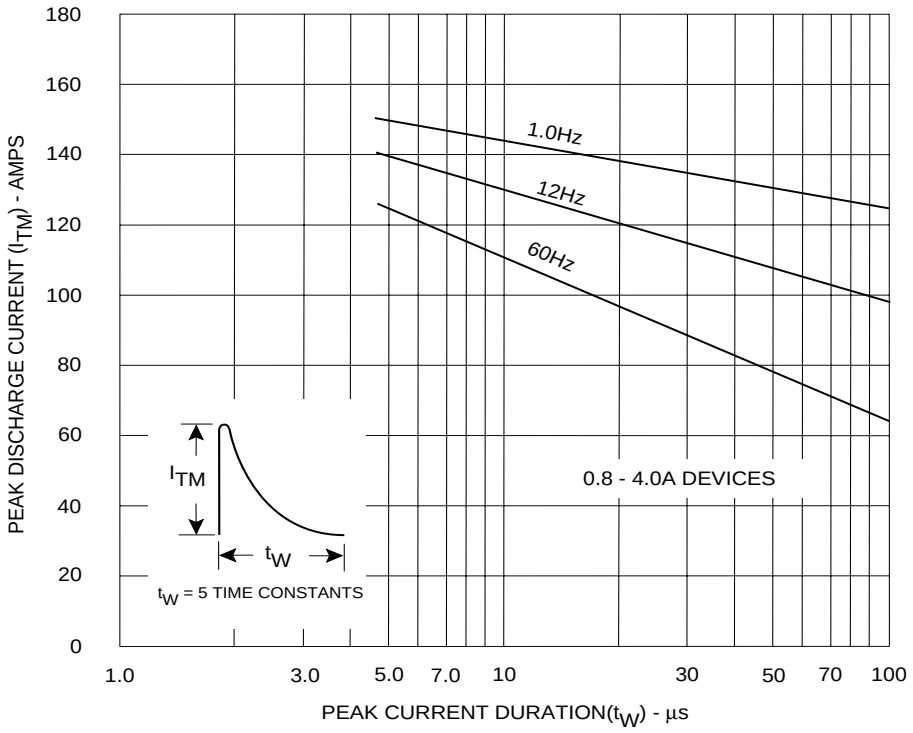


Figure 5.20 Peak Repetitive Capacitor Discharge Current

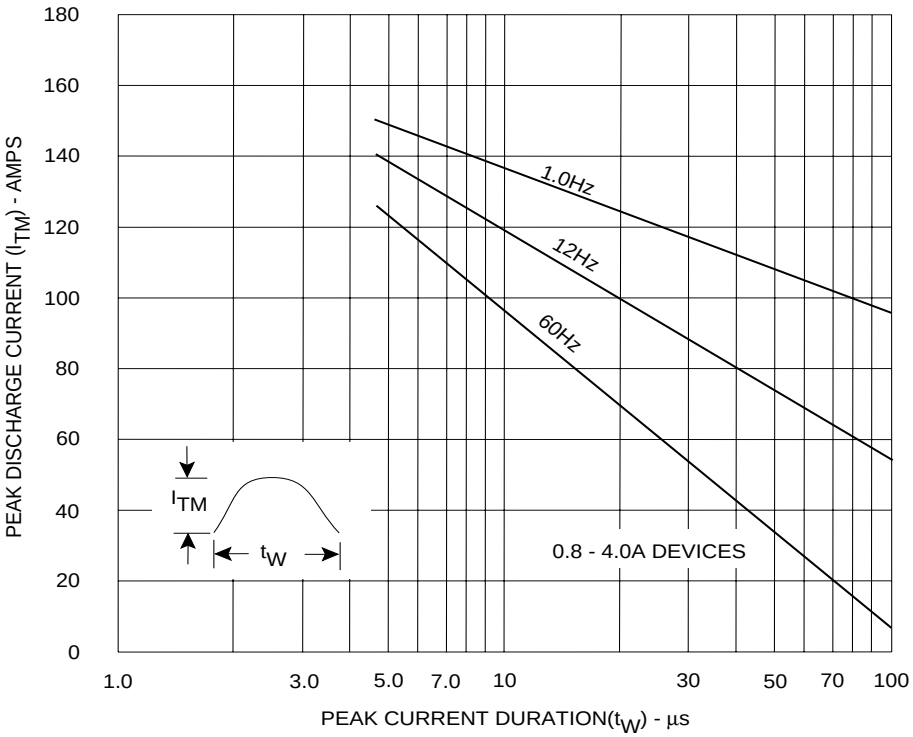


Figure 5.21 Peak Repetitive Sinusoidal Curve